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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Akkerman et al.

Serial No.: 10/701,183

Filed: November 4, 2003

For: DEVICES HAVING LARGE ORGANIC  
SEMICONDUCTOR CRYSTALS AND  
METHODS OF MAKING THE SAME

Group: 2871

Examiner: Not Yet Assigned

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date set forth below:

Signed: Marianna Tortorelli

Name: Marianna Tortorelli

Date: June 14, 2004

Durham, North Carolina  
June 14, 2004

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INFORMATION DISCLOSURE STATEMENT UNDER § 197(a)

Sir:

This Information Disclosure Statement is being filed before a first Official Action has been mailed in this case.

Pursuant to 37 C.F.R. 1.56, 1.97 and 1.98, applicant's attorney wishes to bring to the attention of the Patent and Trademark Office the following items listed on the accompanying Forms PTO/SB/08A and PTO/SB/08B.

## ITEMS

|     | <u>Document No.</u>                  | <u>Publication<br/>Date</u> | <u>Patentee/Applicant</u> |
|-----|--------------------------------------|-----------------------------|---------------------------|
| 1.  | U.S. Patent No. 5,192,580            | 03/09/1993                  | Blanchet-Fincher          |
| 2.  | U.S. Patent No. 5,288,528            | 02/22/1994                  | Blanchet-Fincher          |
| 3.  | U.S. Patent No. 5,347,144            | 09/13/1994                  | Garnier et al.            |
| 4.  | U.S. Patent No. 5,523,192            | 06/04/1996                  | Blanchet-Fincher          |
| 5.  | U.S. Patent No. 5,563,019            | 10/08/1996                  | Blanchet-Fincher          |
| 6.  | U.S. Patent No. 5,625,199            | 04/29/1997                  | Baumbach et al.           |
| 7.  | U.S. Patent No. 5,766,819            | 06/16/1998                  | Blanchet-Fincher          |
| 8.  | U.S. Patent No. 5,840,463            | 11/24/1998                  | Blanchet-Fincher          |
| 9.  | U.S. Patent No. 5,981,970            | 11/09/1999                  | Dimitrakopoulos et al.    |
| 10. | U.S. Patent No. 6,051,318            | 04/18/2000                  | Kwon                      |
| 11. | U.S. Patent No. 6,143,451            | 11/07/2000                  | Blanchet-Fincher          |
| 12. | U.S. Patent No. 6,146,792            | 11/14/2000                  | Blanchet-Fincher et al.   |
| 13. | U.S. Patent No. 6,174,651            | 01/16/2001                  | Thakur                    |
| 14. | U.S. Patent No. 6,265,243            | 07/24/2001                  | Katz et al.               |
| 15. | U.S. Patent No. 6,352,811            | 03/05/2002                  | Patel et al.              |
| 16. | U.S. Patent No. 6,352,812            | 03/05/2002                  | Shimazu et al.            |
| 17. | U.S. Patent No. 6,403,397            | 06/11/2002                  | Katz                      |
| 18. | U.S. Patent No. 6,551,717            | 04/22/2003                  | Katz et al.               |
| 19. | U.S. Publication No. 2002/0149315 A1 | 10/17/2002                  | Blanchet-Fincher          |
| 20. | U.S. Application No. 10/256,885      | 09/27/2002                  | Bao et al.                |
| 21. | U.S. Application No. 10/669,780      | 09/24/2003                  | Bao                       |

|     |                                     |            |                                     |
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| 22. | U.S. Application No. 60/505,533     | 09/24/2003 | Meth                                |
| 23. | U.S. Application No. 60/505,880     | 09/24/2003 | Meth et al.                         |
| 24. | U.S. Application No. 10/671,303     | 09/24/2003 | Bao et al.                          |
| 25. | U.S. Application No. 10/722,613     | 11/26/2003 | Aizenberg et al.                    |
| 26. | PCT Publication No. WO 01/87634 A2  | 11/22/2001 | E.I. du Pont de Nemours and Company |
| 27. | PCT Publication No. WO 02/08801 A1  | 01/31/2002 | E.I. du Pont de Nemours and Company |
| 28. | PCT Publication No. WO 02/092352 A1 | 11/21/2002 | E.I. du Pont de Nemours and Company |

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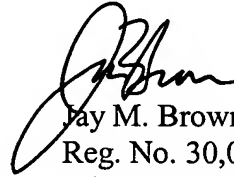
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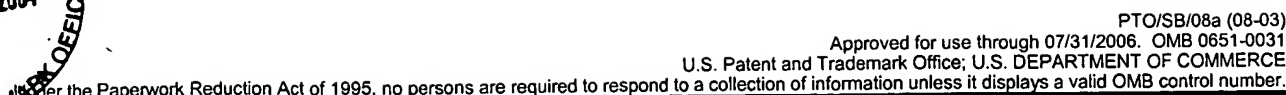
The filing of this Information Disclosure Statement shall not be construed as a representation that a search has been made nor shall it be construed as an admission that the

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Respectfully submitted,

A handwritten signature in black ink, appearing to read "Jay M. Brown", is positioned above the printed name and address.

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# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

**(Use as many sheets as necessary)**

**Complete if Known**

|                    |            |
|--------------------|------------|
| Application Number | 10/701,183 |
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| Filing Date | November 4, 2003 |
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| First Named Inventor | Akkerman et al. |
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| Art Unit | 2871 |
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Examiner Name

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| Attorney Docket Number | 100.2498 |
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## U.S. PATENT DOCUMENTS

| Examiner Initials* | Cite No. <sup>1</sup> | Document Number                            | Publication Date<br>MM-DD-YYYY | Name of Patentee or<br>Applicant of Cited Document | Pages, Columns, Lines, Where<br>Relevant Passages or Relevant<br>Figures Appear |
|--------------------|-----------------------|--|--------------------------------|--|---|
|                    |                       | Number - Kind Code <sup>2</sup> (if known) |                                |  |   |
|                    | 1                     | US- 5,192,580                              | 03/09/1993                     | Blanchet-Fincher                                   |   |
|                    | 2                     | US- 5,288,528                              | 02/22/1994                     | Blanchet-Fincher                                   |   |
|                    | 3                     | US- 5,347,144                              | 09/13/1994                     | Garnier et al.                                     |   |
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|                    | 11                    | US- 6,143,451                              | 11/07/2000                     | Blanchet-Fincher                                   |   |
|                    | 12                    | US- 6,146,792                              | 11/14/2000                     | Blanchet-Fincher et al.                            |   |
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|                    | 14                    | US- 6,265,243                              | 07/24/2001                     | Katz et al.  |   |
|                    | 15                    | US- 6,352,811                              | 03/05/2002                     | Patel et al.                                       |   |
|                    | 16                    | US- 6,352,812                              | 03/05/2002                     | Shimazu et al.                                     |   |
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|                    | 19                    | US- 2002/0149315 A1                        | 10/17/2002                     | Blanchet-Fincher                                   |   |
|                    | 20                    | US- 10/256,885                             | 09/27/2002                     | Bao et al.   |   |

## FOREIGN PATENT DOCUMENTS

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|  |   |    |   | Application Number       | 10/701,183       |
|  |   |    |   | Filing Date              | November 4, 2003 |
|  |   |    |   | First Named Inventor     | Akkerman et al.  |
|  |   |    |   | Art Unit                 | 2871             |
|  |   |    |   | Examiner Name            |                  |
| Sheet  | 2 | of | 5 | Attorney Docket Number   | 100.2498         |

| U.S. PATENT DOCUMENTS |                       |  |                                |  |   |
|-----------------------|-----------------------|--|--------------------------------|--|---|
| Examiner Initials*    | Cite No. <sup>1</sup> | Document Number                            | Publication Date<br>MM-DD-YYYY | Name of Patentee or<br>Applicant of Cited Document | Pages, Columns, Lines, Where<br>Relevant Passages or Relevant<br>Figures Appear |
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| FOREIGN PATENT DOCUMENTS |                       |   |                                |  |   |                |
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|                          | 26                    | WO 01/87634 A2  | 11/22/2001                     | E.I. du Pont de Nemours<br>and Company             |   |                |
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| NON PATENT LITERATURE DOCUMENTS |          |   |                |
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| Examiner Initials*              | Cite No. | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. | T <sup>2</sup> |
|                                 | 29       | AFZALI ET AL., High-Performance, Solution-Processed Organic Thin Film Transistors from a Novel Pentacene Precursor, J. Am. Chem. Soc., 2002, Page(s) 8812-8813, Volume 124  |                |
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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet

4

of

5

**Complete if Known**

Application Number 10/701,183

Filing Date November 4, 2003

First Named Inventor Akkerman et al.

Art Unit 2871

Examiner Name

Attorney Docket Number 100.2498

**NON PATENT LITERATURE DOCUMENTS**

| Examiner Initials* | Cite No. | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.                                 | T <sup>2</sup> |
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Examiner  
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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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| Application Number     | 10/701,183       |
| Filing Date            | November 4, 2003 |
| First Named Inventor   | Akkerman et al.  |
| Art Unit               | 2871             |
| Examiner Name          |                  |
| Attorney Docket Number | 100.2498         |

## NON PATENT LITERATURE DOCUMENTS

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